

TRIAC(Through Hole / Isolated)

# TMG40CQ60J

(Tj=150°C)

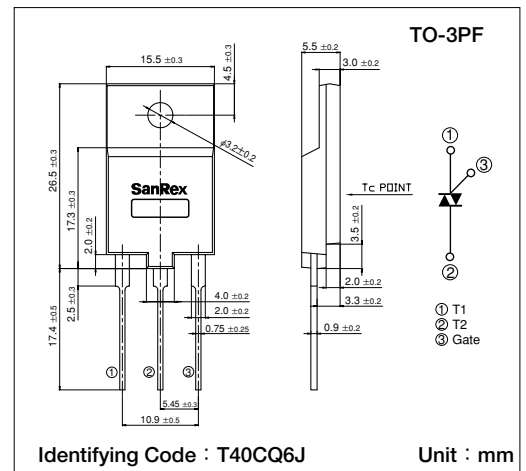
**SanRex** Triac TMG40CQ60J is designed for full wave AC control applications. It can be used as an ON/OFF function or for phase control operation.

## Typical Applications

- Home Appliances : Washing Machines, Vacuum Cleaners, Rice Cookers, Micro Wave Ovens, Hair Dryers, other control applications
- Industrial Use : SMPS, Copier Machines, Motor Controls, Dimmer, SSR, Heater Controls, Vending Machines, other control applications

## Features

- $I_{T(RMS)}=40A$
- High Surge Current
- Lead-Free Package



## Maximum Ratings

(Tj=25°C unless otherwise)

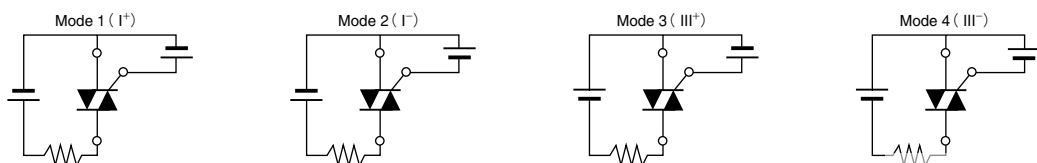
| Symbol              | Item                                 | Reference                                       | Ratings    | Unit             |
|---------------------|--------------------------------------|-------------------------------------------------|------------|------------------|
| V <sub>DRM</sub>    | Repetitive Peak Off-State Voltage    |                                                 | 600        | V                |
| I <sub>T(RMS)</sub> | R.M.S. On-State Current              | T <sub>c</sub> =98°C                            | 40         | A                |
| I <sub>TSM</sub>    | Surge On-State Current               | One cycle, 50Hz/60Hz, Peak value non-repetitive | 380/420    | A                |
| I <sup>2</sup> t    | I <sup>2</sup> t (for fusing)        |                                                 | 730        | A <sup>2</sup> S |
| P <sub>GM</sub>     | Peak Gate Power Dissipation          |                                                 | 10         | W                |
| P <sub>G(AV)</sub>  | Average Gate Power Dissipation       |                                                 | 1          | W                |
| I <sub>GM</sub>     | Peak Gate Current                    |                                                 | 3          | A                |
| V <sub>GM</sub>     | Peak Gate Voltage                    |                                                 | 10         | V                |
| V <sub>ISO</sub>    | Isolation Breakdown Voltage (R.M.S.) | A.C. 1 minute                                   | 1500       | V                |
| T <sub>j</sub>      | Operating Junction Temperature       |                                                 | -40 ~ +150 | °C               |
| T <sub>stg</sub>    | Storage Temperature                  |                                                 | -40 ~ +150 | °C               |
|                     | Mass                                 |                                                 | 5.6        | g                |

## Electrical Characteristics

(Tj=25°C unless otherwise)

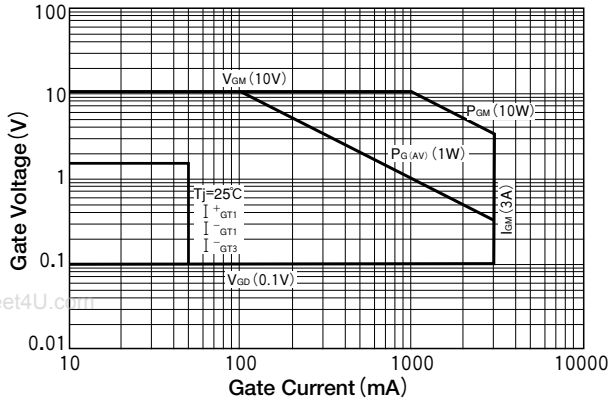
| Symbol            | Item                                                      | Reference                                  | Ratings |      |      | Unit |
|-------------------|-----------------------------------------------------------|--------------------------------------------|---------|------|------|------|
|                   |                                                           |                                            | Min.    | Typ. | Max. |      |
| IDRM              | Repetitive Peak Off-State Current                         | VD=VDRM, Single phase, half wave, Tj=150°C |         |      | 8    | mA   |
| VTM               | Peak On-State Voltage                                     | It=60A, Inst. measurement                  |         |      | 1.4  | V    |
| IGT1 <sup>+</sup> | 1                                                         | VD=6V, RL=10Ω                              |         |      | 50   | mA   |
| IGT1 <sup>−</sup> | 2                                                         |                                            |         |      | 50   |      |
| IGT3 <sup>+</sup> | 3                                                         |                                            |         |      | —    |      |
| IGT3 <sup>−</sup> | 4                                                         |                                            |         |      | 50   |      |
| VGT1 <sup>+</sup> | 1                                                         |                                            |         |      | 1.5  | V    |
| VGT1 <sup>−</sup> | 2                                                         |                                            |         |      | 1.5  |      |
| VGT3 <sup>+</sup> | 3                                                         |                                            |         |      | —    |      |
| VGT3 <sup>−</sup> | 4                                                         |                                            |         |      | 1.5  |      |
| VGD               | Non-Trigger Gate Voltage                                  | Tj=150°C, Vd=½VDRM                         | 0.1     |      |      | V    |
| (dv/dt)c          | Critical Rate of Rise of Off-State Voltage at Commutation | Tj=150°C, [di/dt]c=−20A/ms, VD=⅔VDRM       | 5       |      |      | V/μs |
| IH                | Holding Current                                           |                                            |         | 30   |      | mA   |
| Rth               | Thermal Resistance                                        | Junction to case                           |         |      | 1.1  | °C/W |

Trigger mode of the triac

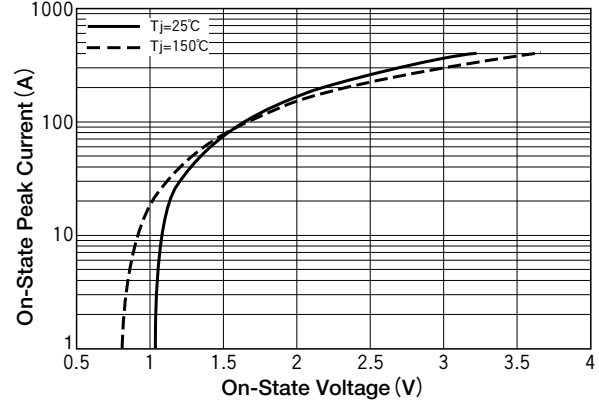


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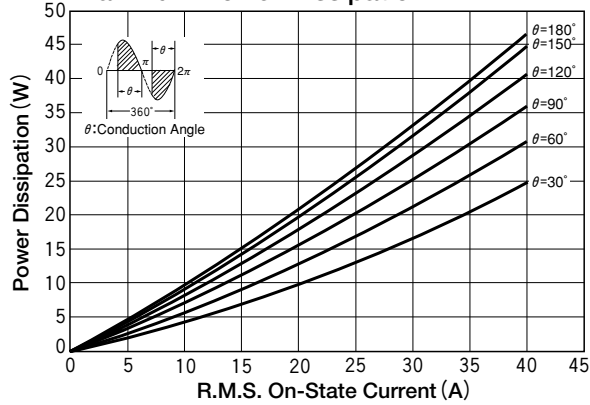
### Gate Characteristics



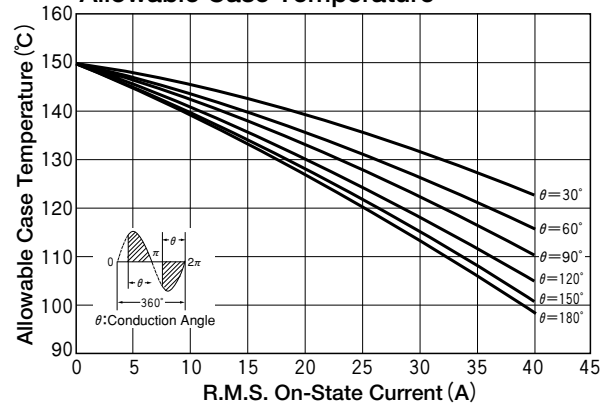
### On-State Characteristics



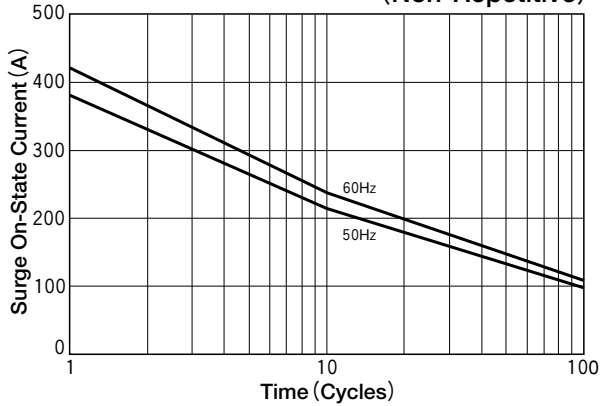
### R.M.S. On-State Current vs Maximum Power Dissipation



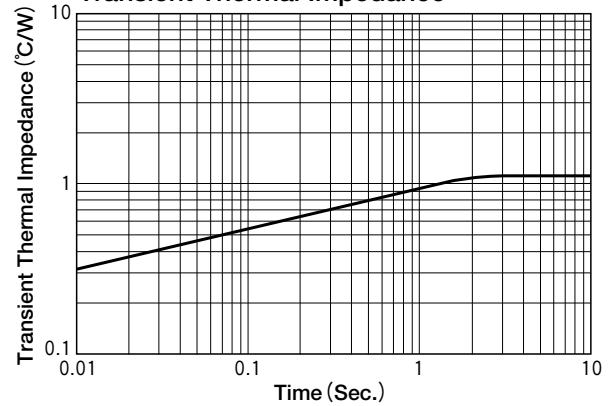
### R.M.S. On-State Current vs Allowable Case Temperature



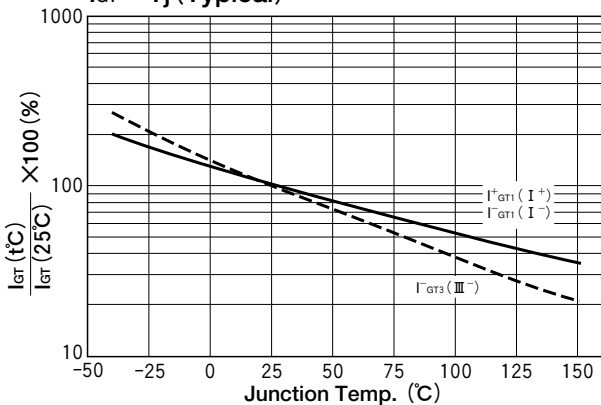
### Surge On-State Current Rating (Non-Repetitive)



### Transient Thermal Impedance



### $I_{GT} - T_j$ (Typical)



### $V_{GT} - T_j$ (Typical)

